# NSN 5961-00-717-7837

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Inclosure Material:

Metal

**Overall Length:** 

0.546 inches

# **Overall Diameter:**

1.046 inches

#### **Mounting Facility Quantity:**

1

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

# Features Provided:

Hermetically sealed case

Thread Size:

0.312 inches

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

150.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, emitter-to-base, collector open and 150.0 breakdown voltage, collector-to-emitter, base open

#### **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 1.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

Fiig:

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